

Electrical Parameter Integration

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PMIC *Power Management Integration Center*



Dartmouth Magnetics
and Power Electronics
Research Group

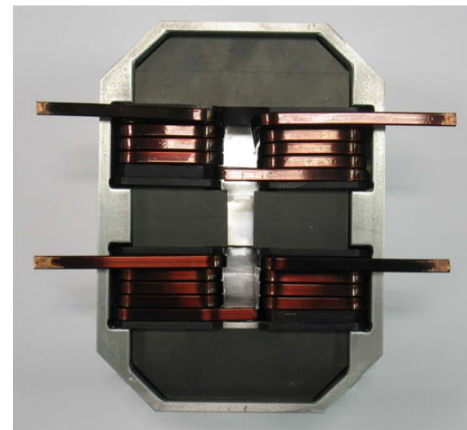
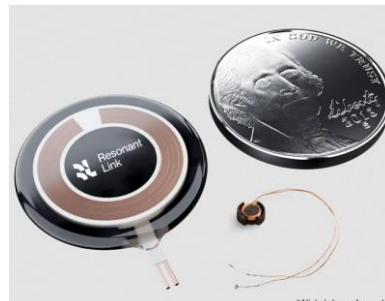
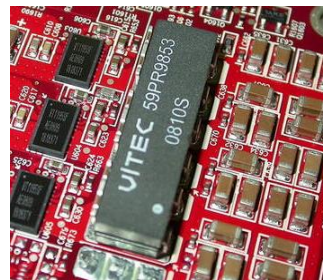
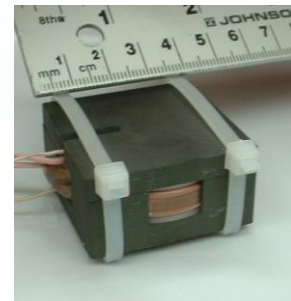
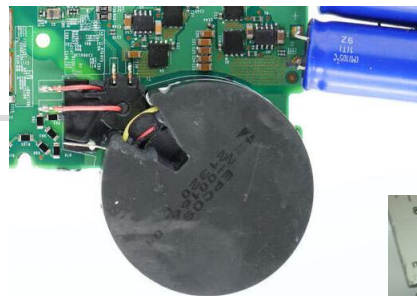


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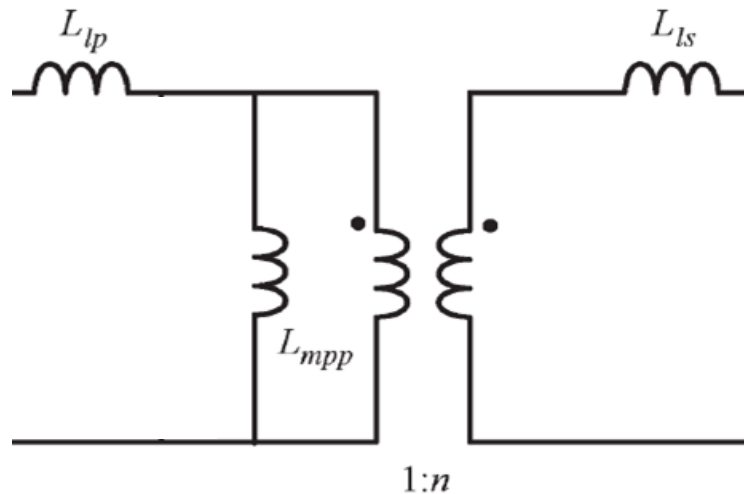
Types of Integration

- Multiple functions from one component.
 - Transformer “parasitic” inductances used for circuit operation, reducing component count
 - Coupled inductors to enhance circuit and magnetics performance
 - Combine L and C functions
- Integration of multiple objectives and constraints in a design process.



Using transformer parasitic L

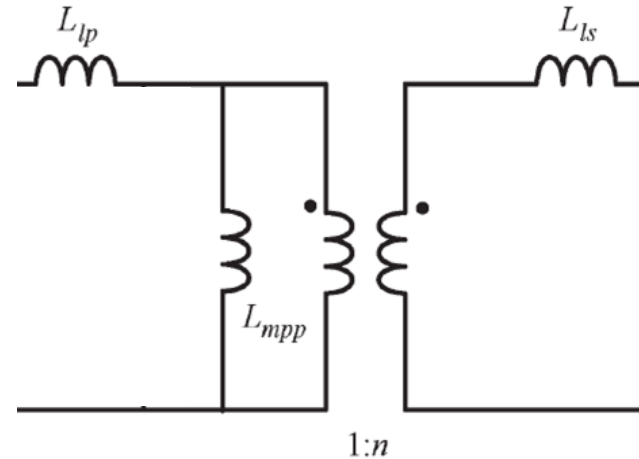
- “Parasitic” inductances:
 - Leakage
 - Magnetizing
- If you need inductor(s) and a transformer, it’s usually an option.
 - Leakage: for resonant converters.
 - Magnetizing: for flyback or resonant converters.
- Both can be adjusted in design.



Matrix vs. T-model

- Both capture full behavior (Assuming linear, lossless, and no capacitance)
- Matrix: 3 degree of freedom vs. Transformer: 4 degrees of freedom.
 - Can choose one parameter arbitrarily.
 - Common choice: n = the physical turns ratio.

$$\begin{bmatrix} v_p \\ v_s \end{bmatrix} = \begin{bmatrix} L_p & M \\ M & L_s \end{bmatrix} \frac{d}{dt} \begin{bmatrix} i_p \\ i_s \end{bmatrix}$$



Reference: Guillod, T., Krismer, F. & Kolar, J.W. "Magnetic Equivalent Circuit of MF Transformers: Modeling and Parameters Uncertainties," Electr Eng (2018) 100: 2261. <https://doi.org/10.1007/s00202-018-0701-0>



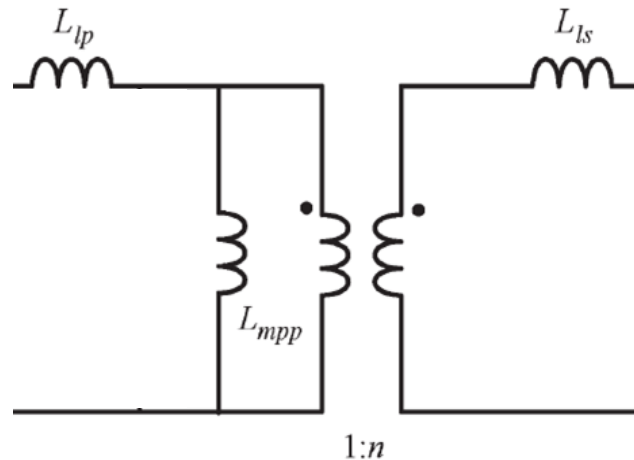
Coupling factor k

$$\begin{bmatrix} v_p \\ v_s \end{bmatrix} = \begin{bmatrix} L_p & M \\ M & L_s \end{bmatrix} \frac{d}{dt} \begin{bmatrix} i_p \\ i_s \end{bmatrix}$$

- Good simplification? **No.**
- Definition: ratio of mutual to self inductance.
Specifically,
the geometric mean: $k = M / \sqrt{L_p L_s}$
- Problems with k :

Spec calls for high k , a transformer with “high coupling”:

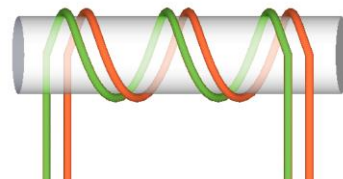
- Might mean low leakage is needed
- Or, might mean high magnetizing inductance is needed.
- If you improve the wrong one, you can get high k without meeting the real spec.



Spec what you want: high or low L_m ; ~~Improve k ?~~ high or low L_ℓ .



- “A high-permeability core improves coupling factor”.
 - It increases magnetizing inductance, but does not reduce leakage.
- “A bifilar winding improves coupling factor”.
 - It increases magnetizing inductance, but does not reduce leakage.
- If you ask for high k (or low k), you might not get what you really need.





An exception: when k is useful.

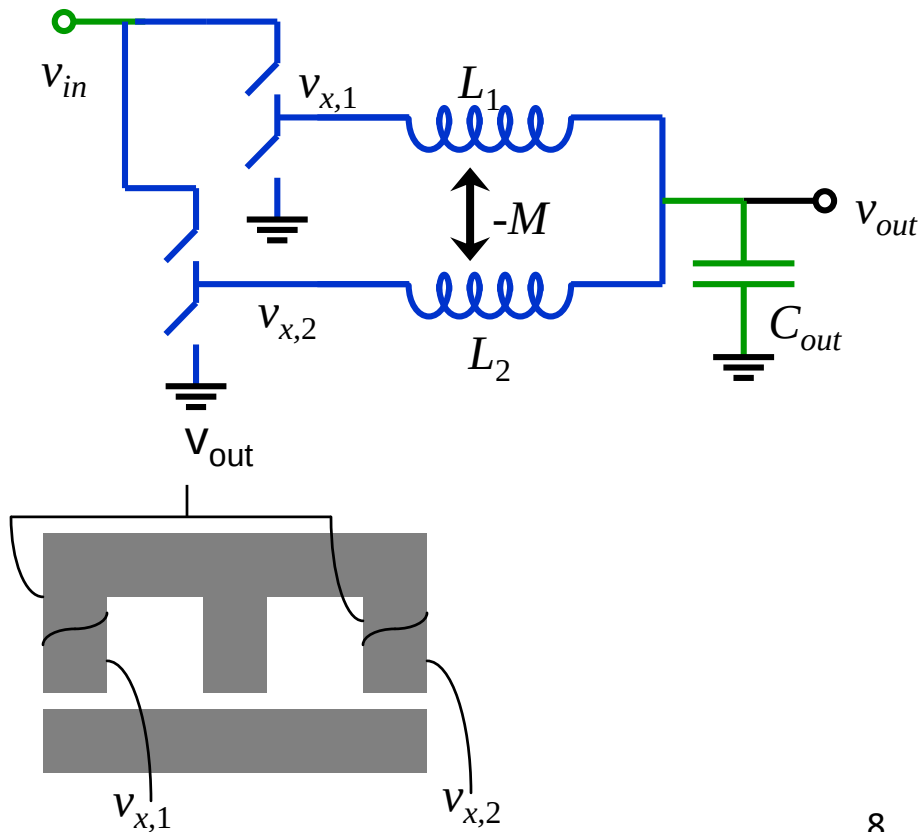
Air-core transformers and wireless power systems:

- Without saturation or (much) core loss, N (number of turns) can be chosen without considering B . Changing N just scales all impedances.
- If k is good (what that means depends on the application), adjusting N allows setting both L_ℓ and L_m values to meet the spec.
- **Design process:**
 - Vary geometry to get k you want.
 - Vary N to get the right L_ℓ and L_m values.

Example where k is misleading

Coupled inductor multi-phase buck.

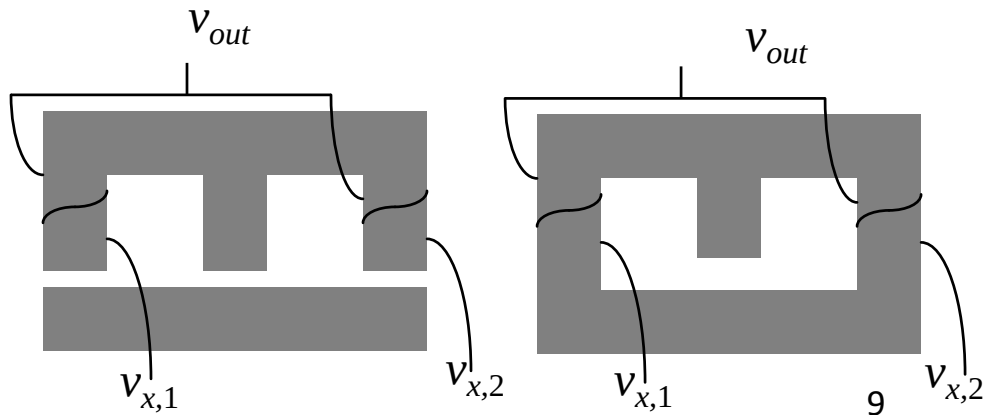
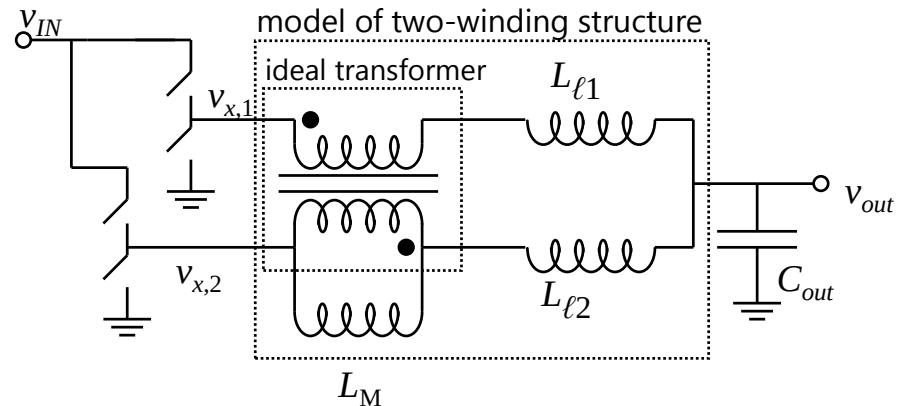
- Early insight: coupling can help.
- Naïve design approach:
Find optimal value of k ...
but arbitrarily holding L_{self} constant.



Example where k is misleading

Coupled inductor multi-phase buck.

- Early insight: coupling can help.
- Naïve design approach:
Find optimal value of k ...
but arbitrarily holding L_{self} constant.
 - Low k means no benefit, but high k would mean low leakage and excessive ripple: chose moderate k .
- **Better approach:**
Consider L_M and L_{leak} independently.
 - Maximize L_M : ungapped structure.
 - Choose L_{leak} based on ripple, transient, and size trade-offs—all mitigated by coupling.



Separately design for L_m and L_ℓ

- L_m is easy: add a gap or adjust the gap to hit the target value.
 - Tradeoffs between core loss, winding loss, and saturation effected via gap and number of turns, as in standard inductor design.
- L_ℓ design can be more challenging...

Design for L_ℓ

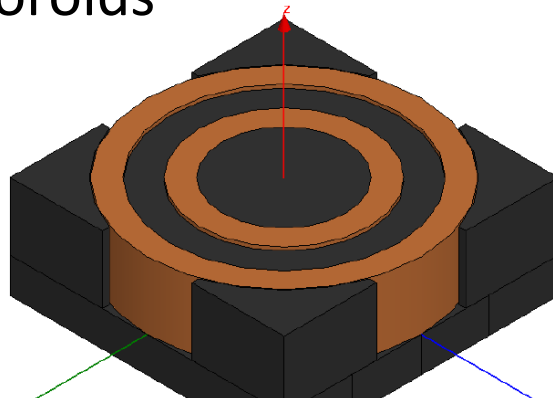
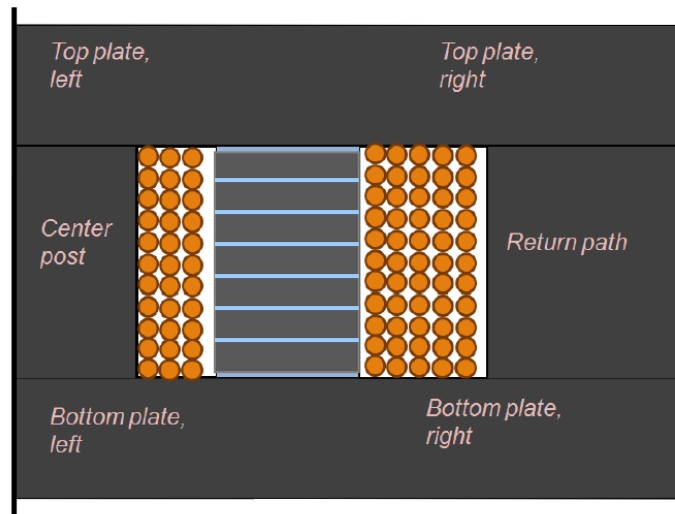
- For low L_ℓ
 - Interleaving (respect symmetry) and/or large winding breadth b .
Limitation: capacitance.
 - Fewer turns: need larger core area to limit flux density for saturation and core loss.
- For higher L_ℓ
 - Winding configuration
 - Add a shunt
 - Use more turns--reduced core loss mitigates increased winding loss.

Performance improvement

Functional integration

Shunt to add leakage

- Adjust gaps to get any L_ℓ value.
- Fringing flux increases winding loss: in this design mitigated by carefully chosen litz wire.
- Or, stack multiple thin shunt toroids to get “quasi distributed gap”.
- Consider cooling for floating shunt.

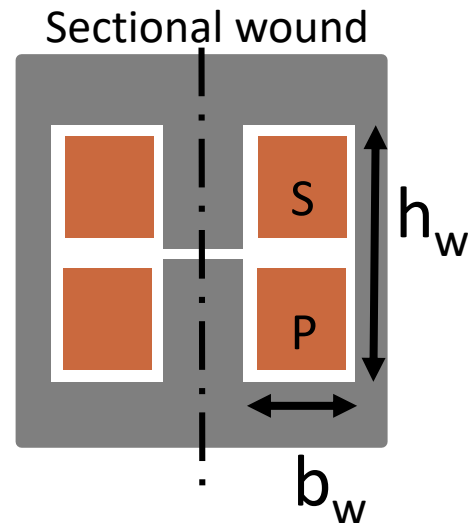
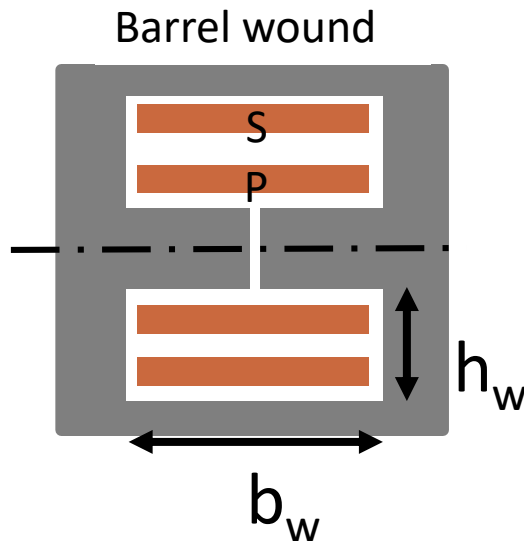


Winding orientation effect

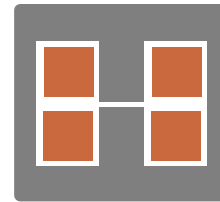
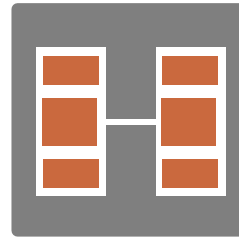
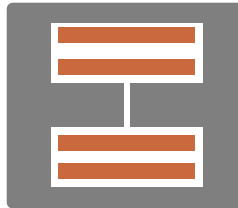
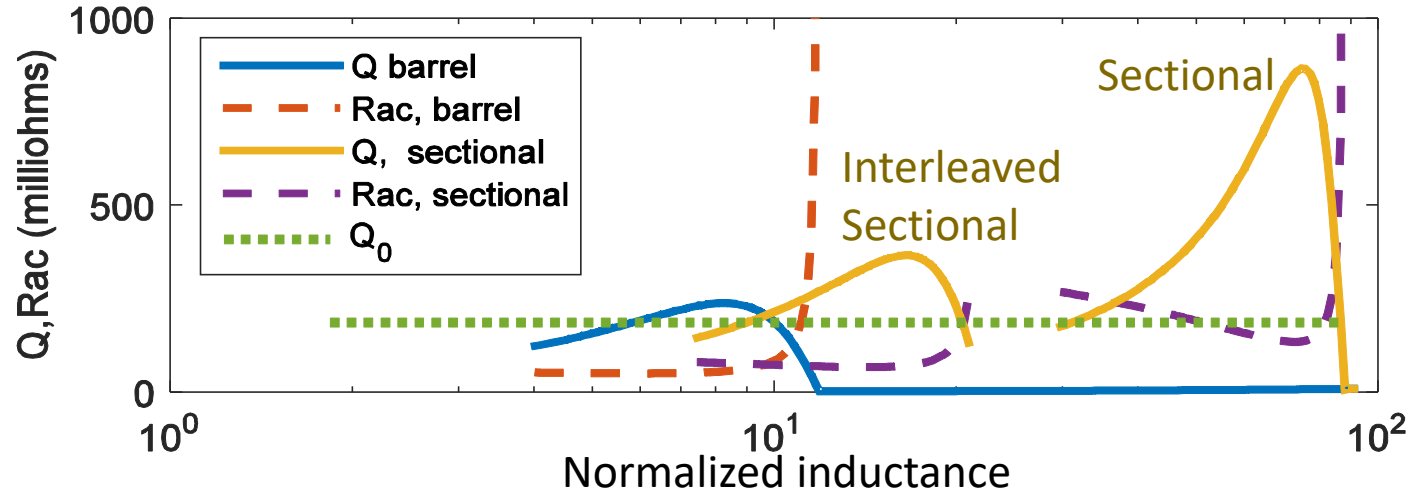
- Sectional wound gives much higher leakage.
- Can tune winding build and spacing to set leakage.

$$L_{leak,p} = \frac{k_L}{b_w} \left(h_w - \left(\frac{2}{3} \right) h_{ps} \right)$$

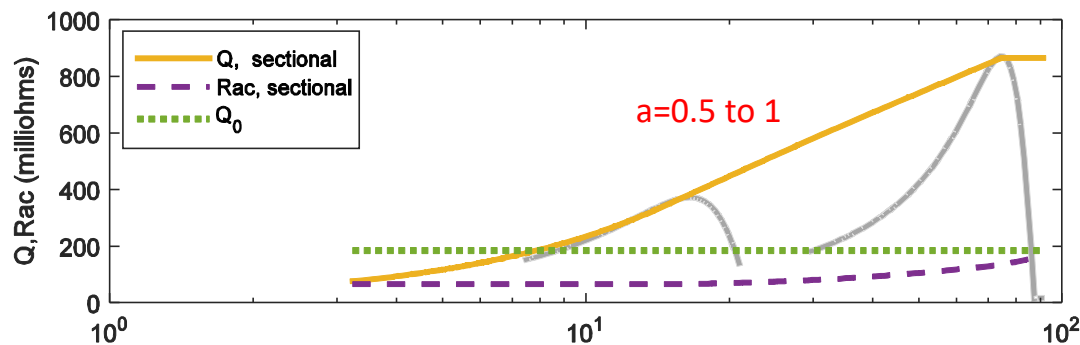
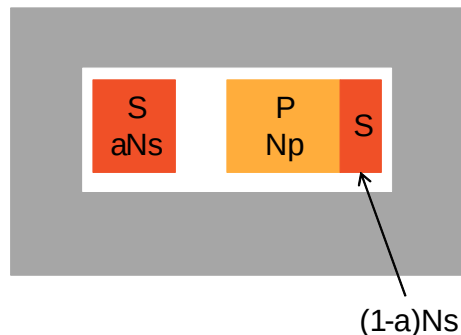
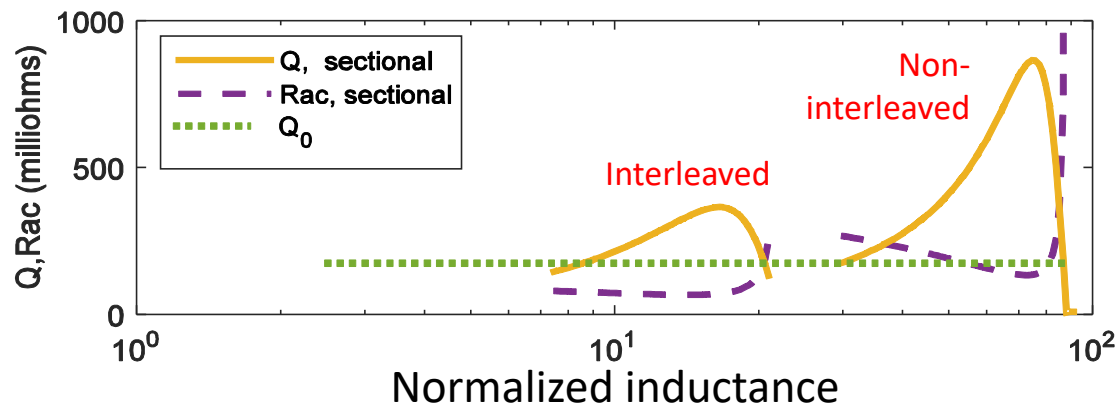
$$k_L = \mu_0 N_p^2 \ell_{turn} \quad h_{ps} = h_p + h_s$$



Design options



What if the spec is between these peaks?



Comments on integrating inductive functions

- Design for the L_m and L_ℓ you want, separately, rather than looking at k .
- L_m is easily adjusted with a gap.
- L_ℓ can be reduced with interleaving, limited only by capacitance, and with larger A_c to allow small N .
- L_ℓ can be increased with a shunt or with a “sectional” winding arrangement.
 - Partial interleaving can adjust leakage without hurting R_{ac} .

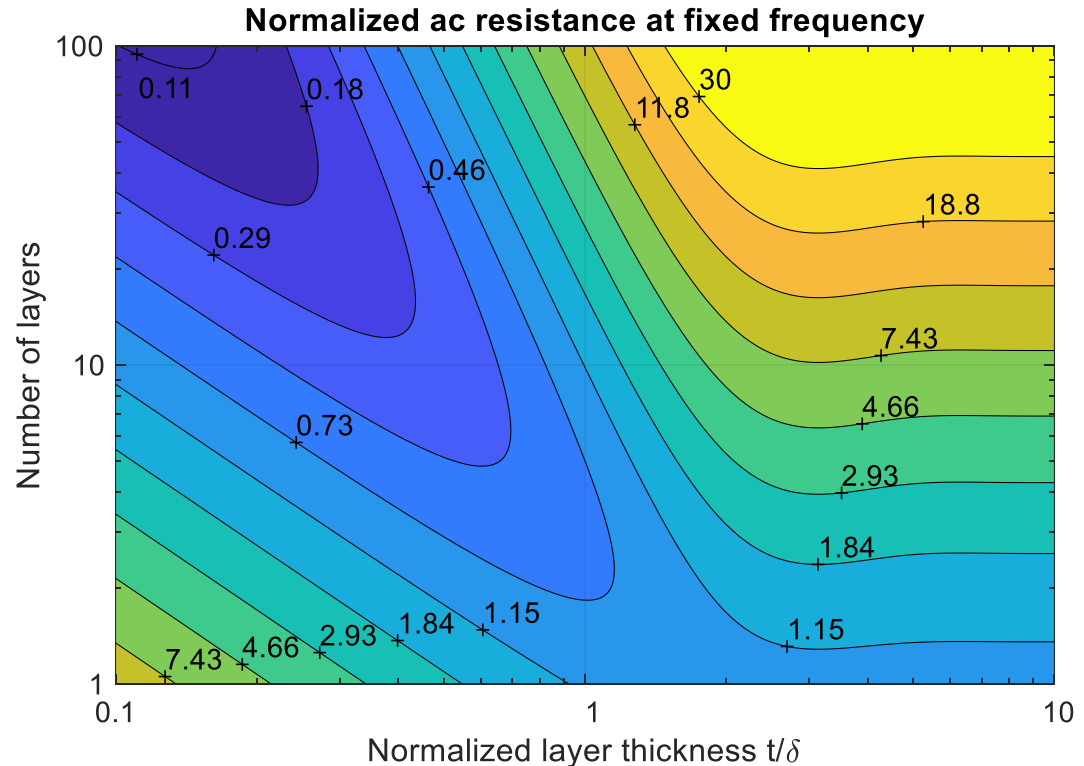
Integration of capacitance

- Proliferation of types of resonant converters.
- Need C and well as L.
- Magnetic components have dielectrics in them anyway—can we use these to form the capacitor(s) for a resonant converter?
 - Yes, we can: has been demonstrated back in the 1990s by Ferreira, Van Wyk, and others.
 - But is it useful to do so?
 - Capacitors are cheap and have low loss anyway.
 - What if combining L and C could improve ***magnetics*** performance?

For excellent low ac resistance we need conductor dimensions $\ll$ skin depth δ



- Litz wire is great, but
 - It's expensive
 - For excellent MHz performance we want dimensions smaller than the $\sim 40 \mu\text{m}$ of fine litz strands.
 - We want $< 20 \mu\text{m}$, or even $< 5 \mu\text{m}$



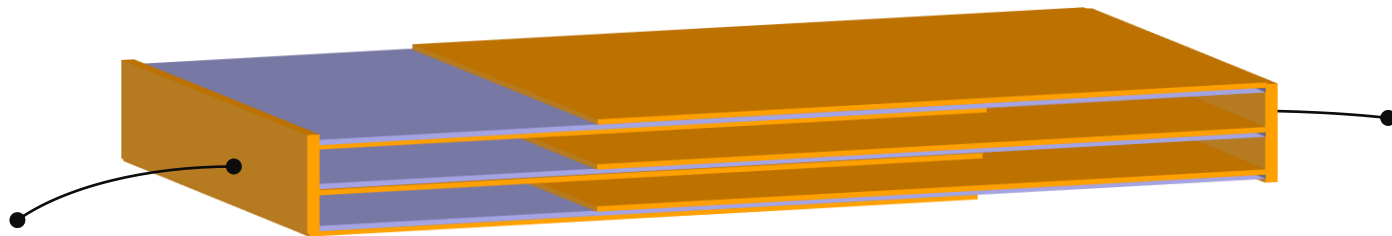
Foil: $< 20 \mu\text{m}$ at low cost

- Easy to get thickness $\ll$ skin depth.
 - Freestanding foil down to $\sim 6 \mu\text{m}$.
 - On plastic-film substrates for easier handling down to $\ll 1 \mu\text{m}$.
- Thin layers have high dc resistance—
need many in parallel.
- Challenges:
 - Achieving uniform current density—laterally and among layers.
 - High capacitance between layers.
 - Terminations



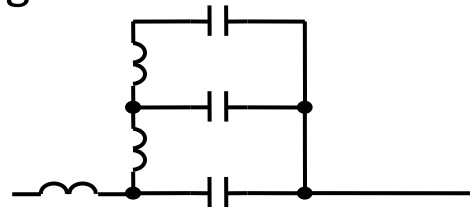
One concept for MHz foil windings: capacitive ballasting

- Overlapping insulated layers create series capacitance for each layer.



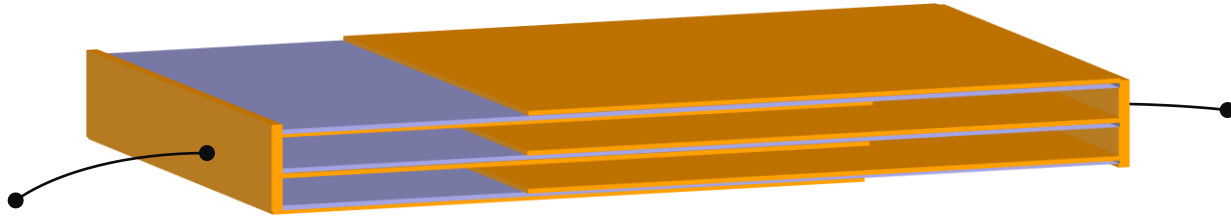
Cartoon—not actual design

- Capacitive ballasting forces equal current sharing.
- Goal in previous integrated LC structures: combine functions in single volume.
- Our goal: Not just integration, but creating a new type of ultra-low-loss winding.
- Best application fit: resonator (LC tank).

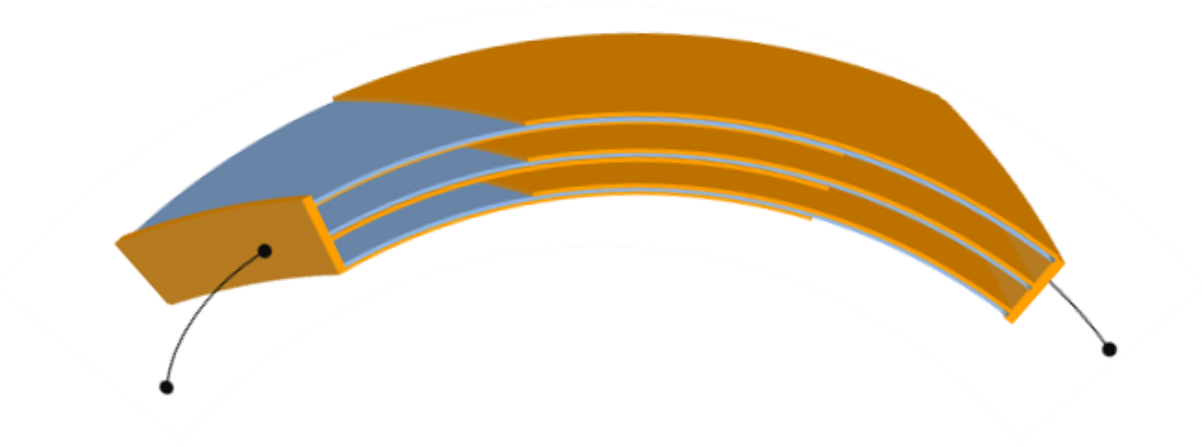




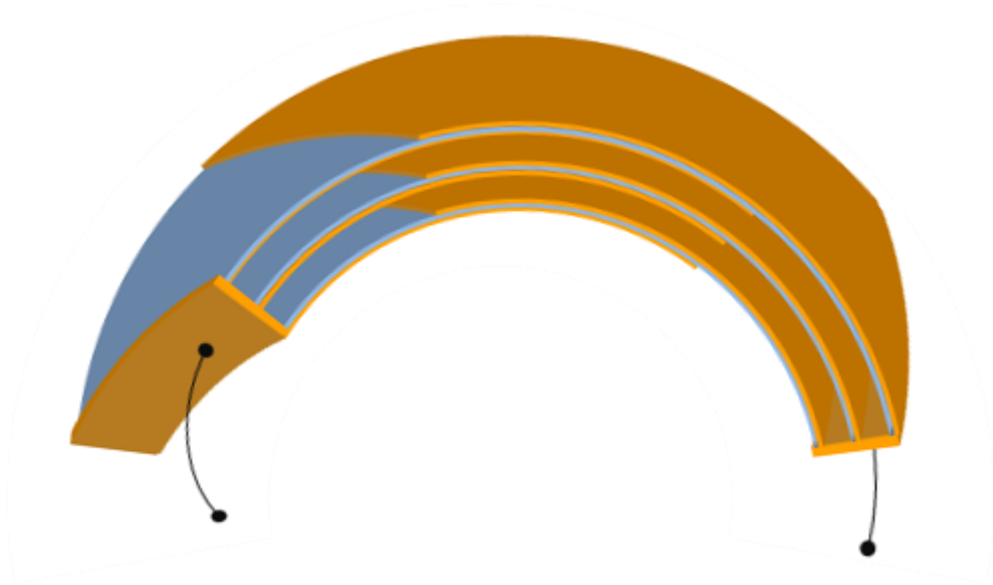
Can we make an inductor coil out of this?



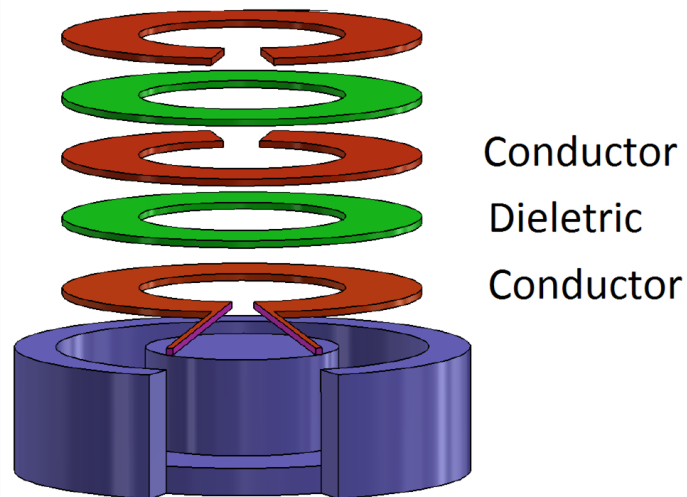
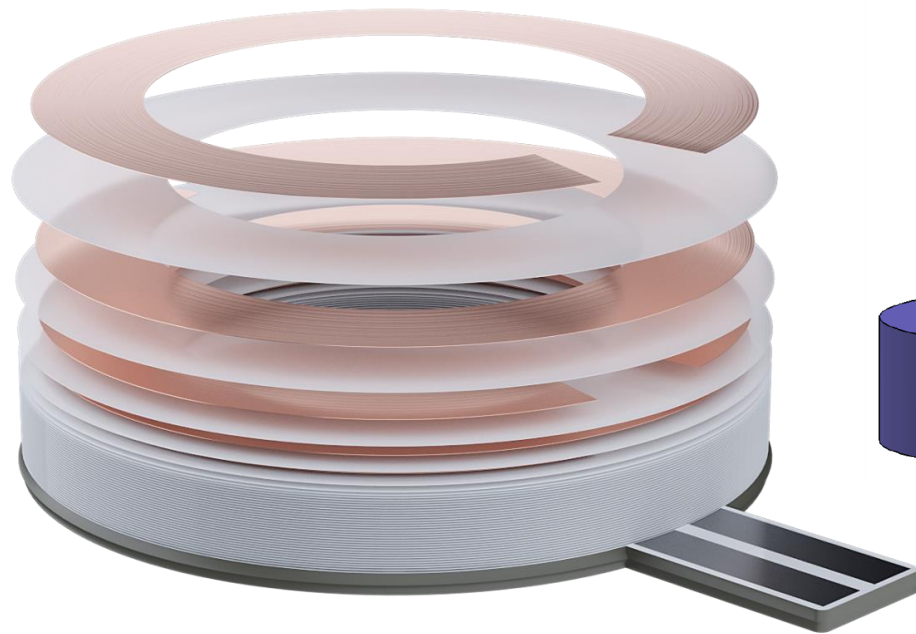
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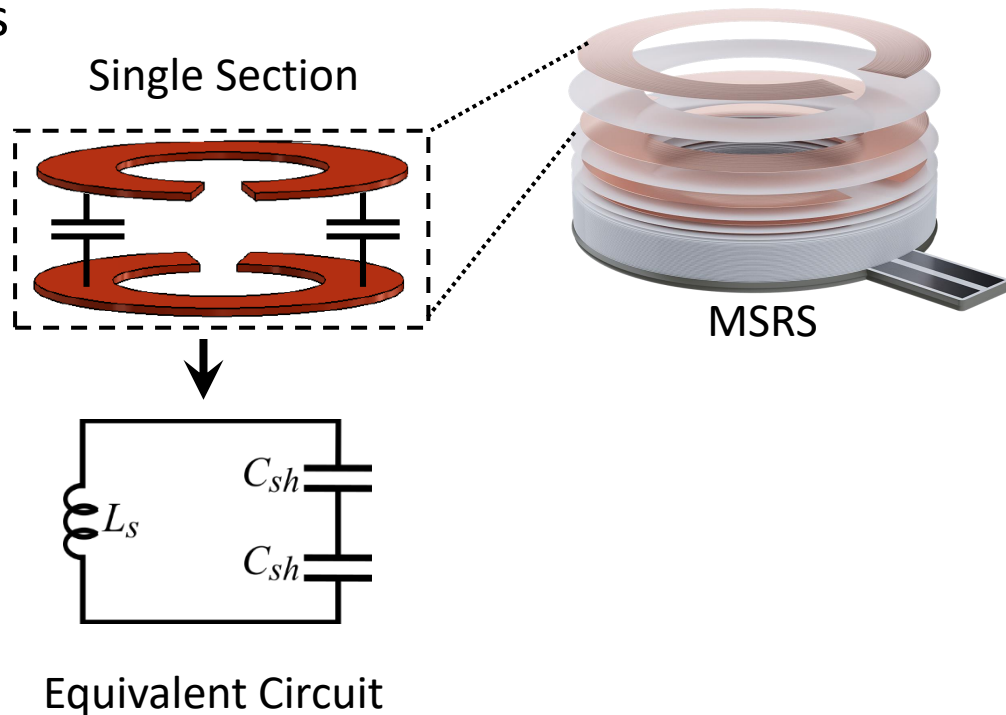


Capacitively ballasted multilayer self-resonant structure (MSRS)



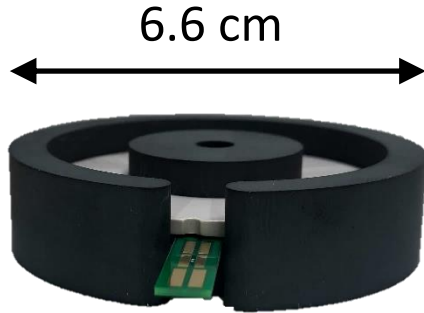
Multilayer self-resonant structure (MSRS) functionality

- Stack of LCC resonator loops
- All magnetically coupled.
- Solves coil challenges and achieves very high Q
 - Thin foils minimize skin & proximity effects
 - No additional losses in capacitor plates.
 - No vias or high-current or voltage terminations.



*9 patents pending or granted

Example implementation



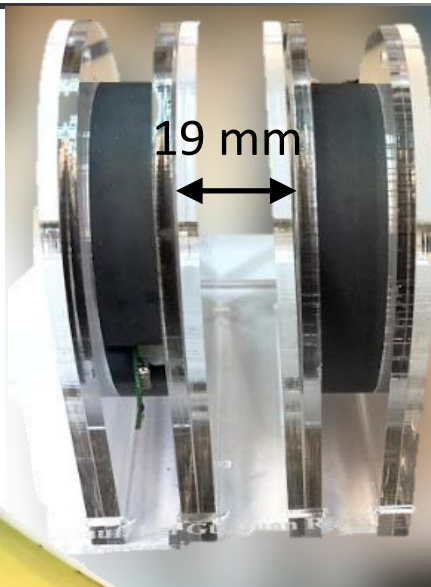
- $Q = 1699$
- Figure of merit
$$Q_d = \frac{Q}{d} = 257 \text{ cm}^{-1}$$
- 6X highest Q_d in the literature.

Example implementation



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Example implementation



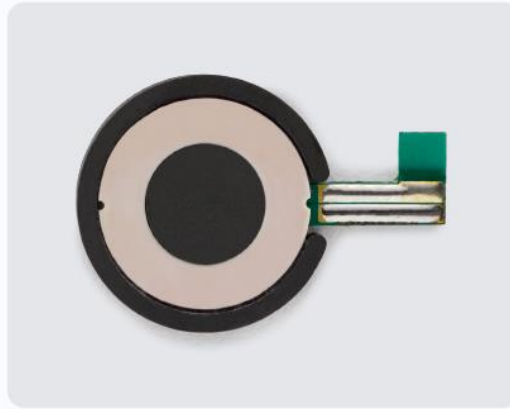
- $Q = 1699$
- 6X highest Q_d in the literature:
 $Q_d = \frac{Q}{d} = 257 \text{ cm}^{-1}$
- **1 kW at 19 mm,
95% dc-dc efficiency**

Practical implementations

Scales for different applications developed by Resonant Link, Inc.



3 mm Ø



20 mm Ø

$Q_{\text{tank}} = 675$ @
13.56 MHz



57 cm Ø

$Q_{\text{tank}} = 2096$ @
83.8 kHz



Application: Oral diagnostics

Output power: 20 mW

Implant size: 3 mm diameter

Feature: 5% tuning tolerance



Application: Brain-computer interface

Output power: 500 mW (750 mW pk)

Implant size: 60 mm diameter

Feature: 10 kbps bi-directional comm.



Application: Cardiovascular therapy

Output power: 10 W (30 W peak)

Implant size: 60-80 mm diameter

Feature: 5 cm misalignment tolerance



10^{-2}

10^{-1}

1

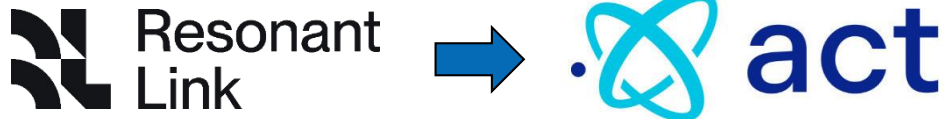
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Maximum Power Delivered (W)

- Low temperature rise and low tissue heating enables applications that couldn't be done before.

Higher power application

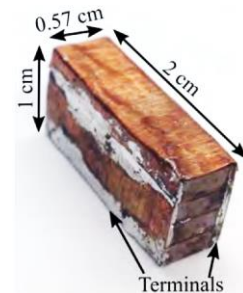
- 19.2 kW, 400 A output
- Air gap up to 10"
- Misalignment +/- 6"



Self resonant components as power-conversion passives

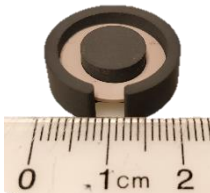
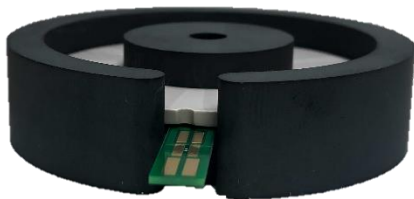
High-density resonant structure, $\sim 1.2 \text{ cm}^3$

- 0.5 m Ω ESR in a 250 V dc rated component.
- Without considering any limitations of today's power switches, over 10 kW would be possible at over 99% efficiency.

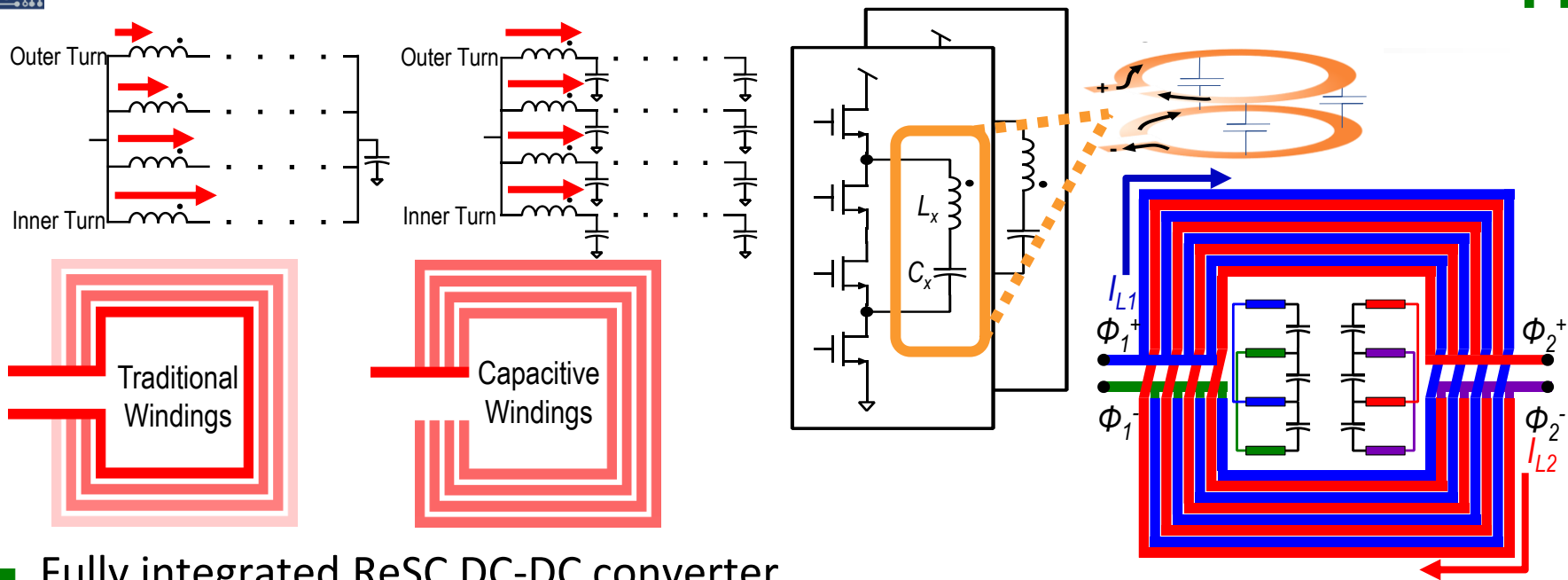


High-Q MLCC-winding components

- Developed for wireless power transfer, $Q = 675 \sim 1699$
- More flexibility to match circuit applications.

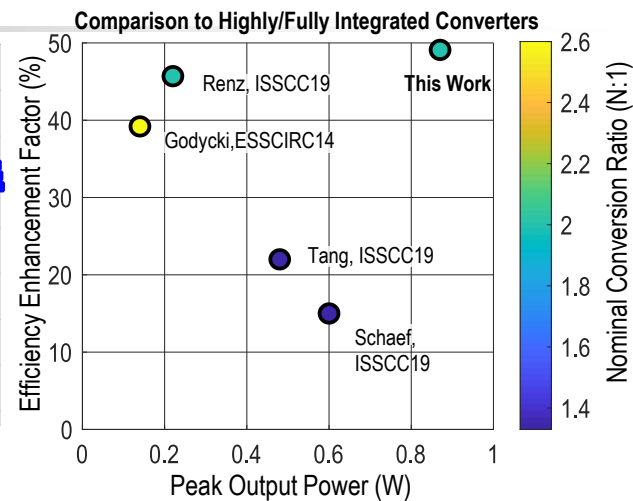
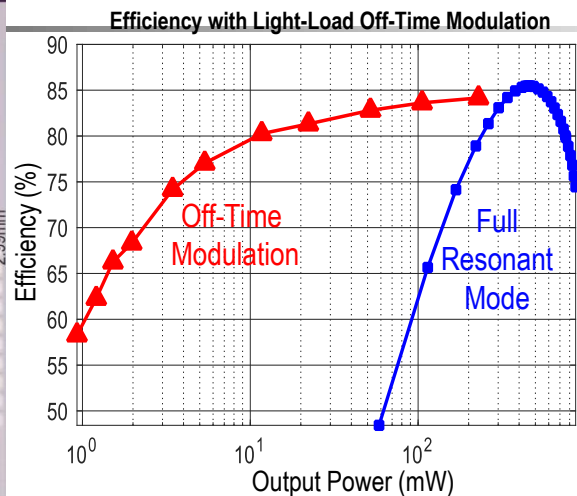
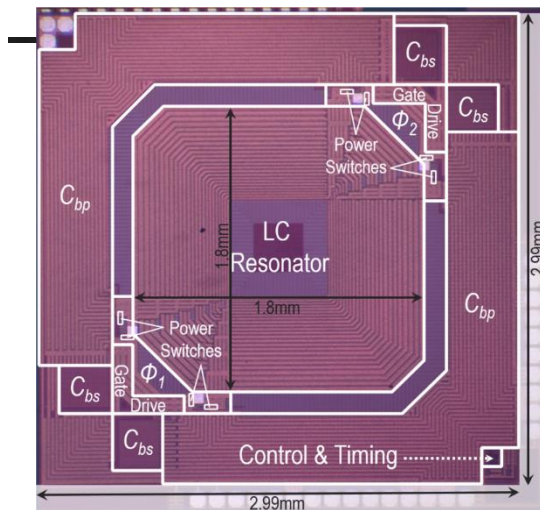


Merged with circuit and fully integrated on die



- Fully integrated ReSC DC-DC converter
- Merged multiphase LC resonator on-chip
- Capacitive ballasting $\rightarrow$ uniform current $\rightarrow$ decreases ESR

Merged and fully integrated—results



- 49.1% efficiency enhancement over LDO
- 2.4–4.4 V in, 1–2.2 V out, 870 mW, 48 MHz
- 85.5% peak efficiency
- 97 mW/mm² (chip area); 267 mW/mm² (resonator area)



Electrical Parameter Integration

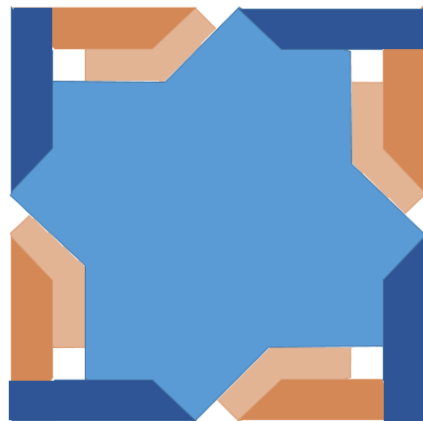
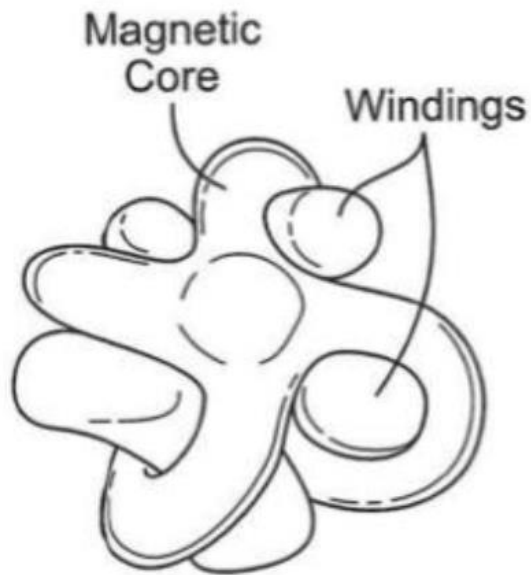
- Design for the L_m and L_ℓ you want, separately, rather than looking at k .
- Integrating functions can be nice, but look for bigger benefits to make it worthwhile:
 - Coupled inductors that circumvent the transient response/ripple tradeoff while reducing size, loss and energy storage.
 - LC structures that use C not only to resonate, but also to ballast current, sharing it between parallel paths, without the twisting used in litz wire.

Shape optimization

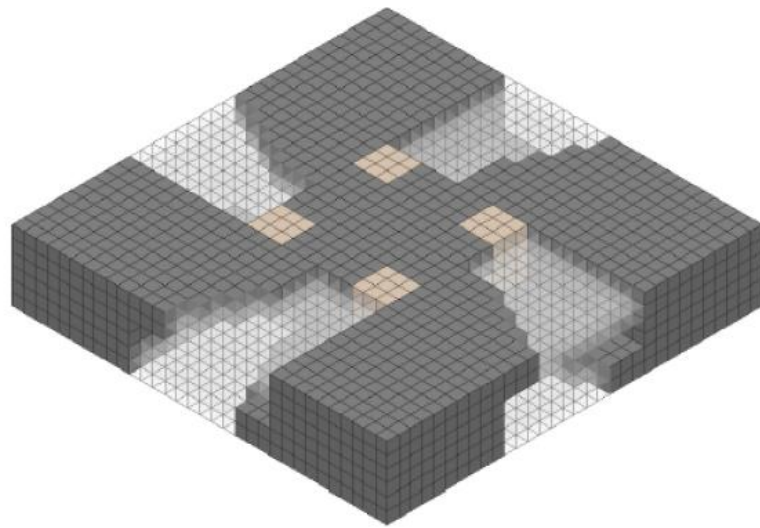
Free shape concept

Add-constraints:

- Drop-in wire for winding
- Two-piece core



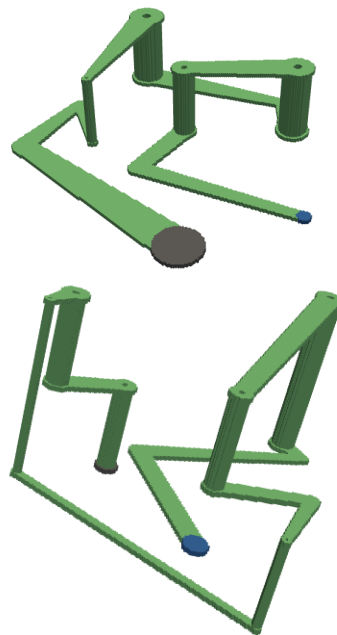
Calculated design



Free shape optimization?

- Optimize air-core inductor on PCB
- OK, we do need constraints:
 - Any 2D shape on each layer + vias.
 - But must be valid—ended up needing 14 rules.
- Also need a fast field solver: FFT Accelerated PEEC method: open source code available.
- Details: presentation by Dr. Thomas Guillod, 11:30 on Th, T36.5 room A312

Valid Geom.

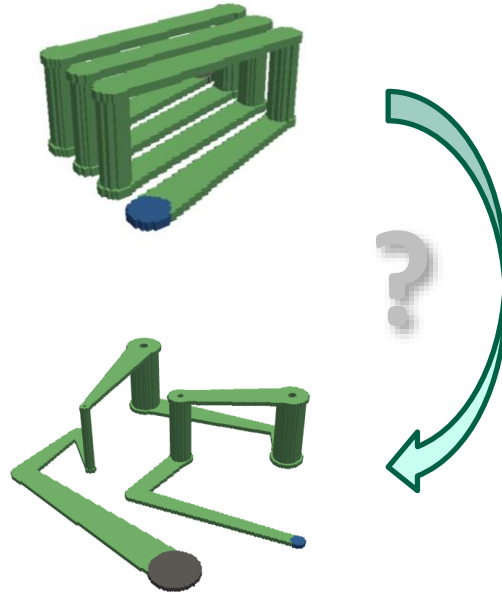


Invalid Geom.

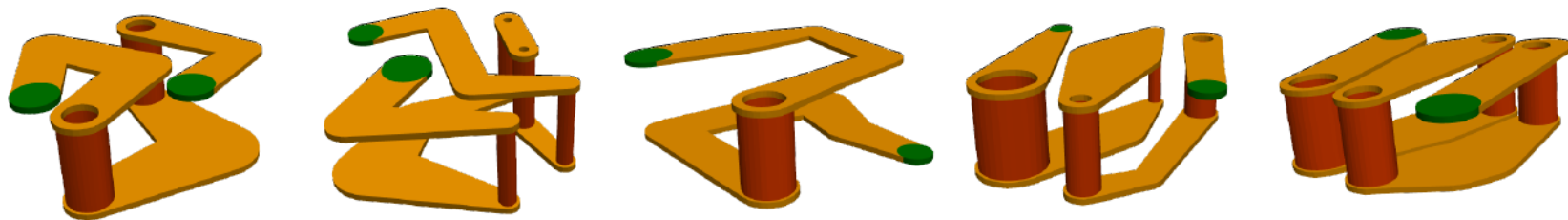
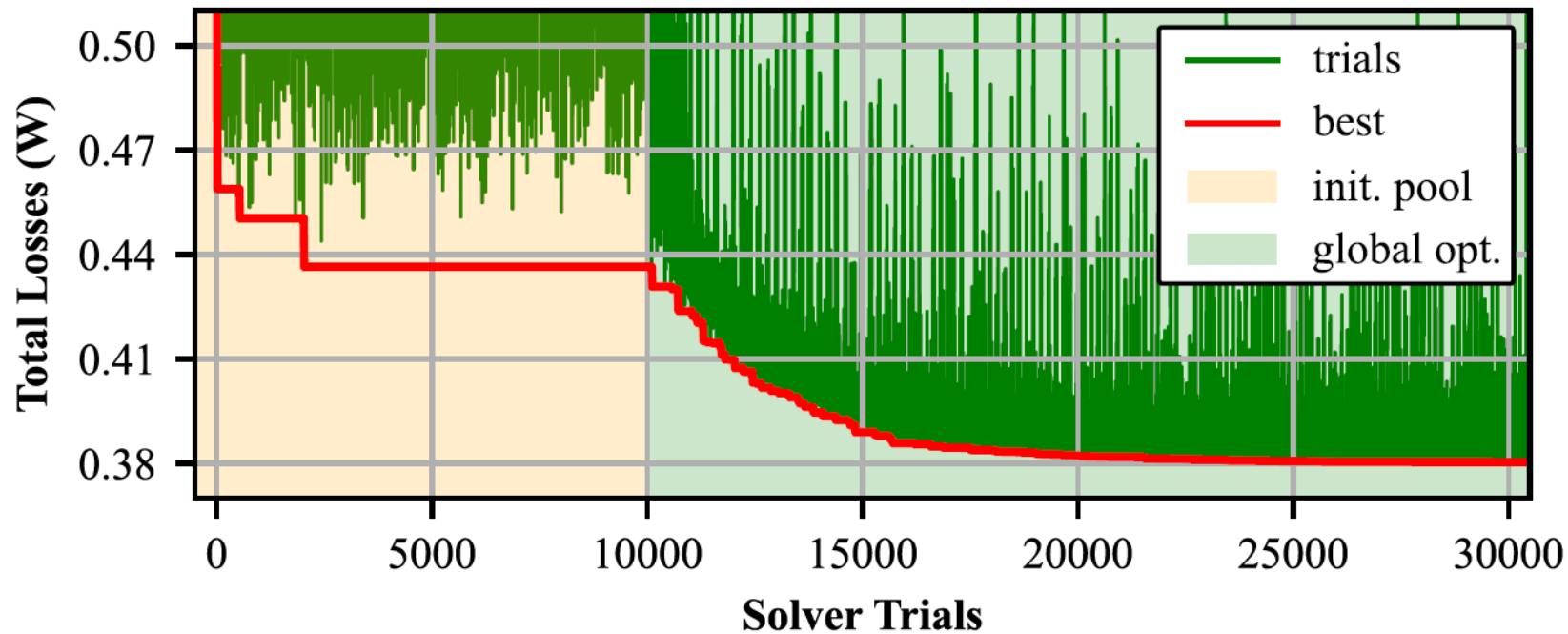




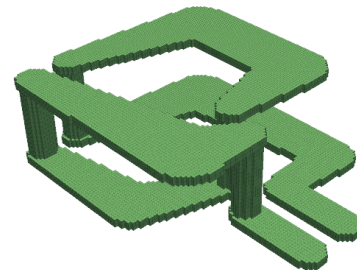
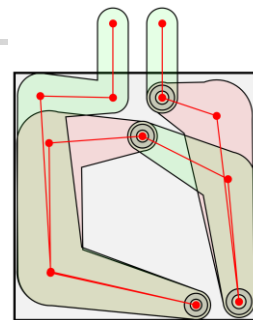
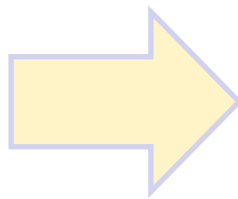
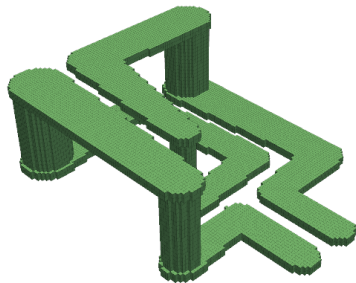
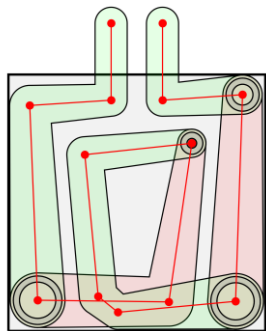
Will it invent something new?



Optimizer Convergence



Add constraints: terminal location and external field limit



	Without Near-Field Opt.		With Near-Field Opt.
Total Efficiency	80.8%	- 2%	78.9%
Inductor Efficiency	89.7%		88.1%
DC Near-Field	1247 A/m	0.45x	441 A/m
AC Near-Field	660 A/m		300 A/m

- Shape optimization is very powerful for addressing constraints

Conclusions

- Electrical Parameter Integration
 - Design for L_m and L_ℓ
 - Look for benefits beyond parts count
- Shape optimization
 - New capabilities emerging.
 - Presentation by Dr. Thomas Guillod,
11:30 on Th, T36.5 room A312